



ELECTRONICS, INC.
 44 FARRAND STREET
 BLOOMFIELD, NJ 07003
 (973) 748-5089
<http://www.nteinc.com>

NTE4512B Integrated Circuit CMOS, 8-Channel Data Selector

Description:

The NTE4512B is an 8-channel data selector in a 16-Lead DIP type package constructed with MOS P-channel and N-channel enhancement mode devices in a single monolithic structure. This data selector finds primary application in signal multiplexing functions. It may also be used for data routing, digital signal switching, signal gating, and number sequencing generation.

Features:

- Noise Immunity = 45% of V_{DD} (Typ)
- Diode Protection on All Inputs
- High Fanout > 50
- Single Supply Operation – Positive or Negative
- 3-State Output (Logic “1”, Logic “0”, High Impedance)
- Supply Voltage Range: 3Vdc to 18Vdc
- Capable of Driving Two Low-Power TTL Loads, One Low-Power Schottky TTL Load or Two HTL Loads Over the Rated Temperature Range

Absolute Maximum Ratings: (Voltages referenced to V_{SS} , Note 1)

DC Supply Voltage, V_{DD}	-0.5 to +18.0V
Input Voltage (All Inputs), V_{in}	-0.5 to V_{DD} to +0.5V
DC Current Drain (Per Pin), I	10mA
Operating Temperature Range, T_A	-55° to +125°C
Storage Temperature Range, T_{stg}	-65° to +150°C

- Note 1. Maximum Ratings are those values beyond which damage to the device may occur.
 Note 2. This device contains circuitry to protect the inputs against damage due to high static voltages or electric fields; however, it is advised that normal precautions be taken to avoid application of any voltage higher than maximum rated voltages to this high impedance circuit.

Electrical Characteristics: (Voltages referenced to V_{SS} , Note 2)

Parameter	Symbol	V_{DD} Vdc	-55°C		+25°C			+125°C		Unit
			Min	Max	Min	Typ	Max	Min	Max	
Output Voltage $V_{in} = V_{DD}$ or 0 $V_{in} = 0$ or V_{DD}	“0” Level V_{OL}	5.0	-	0.05	-	0	0.05	-	0.05	Vdc
		10	-	0.05	-	0	0.05	-	0.05	Vdc
		15	-	0.05	-	0	0.05	-	0.05	Vdc
	“1” Level V_{OH}	5.0	4.95	-	4.95	5.0	-	4.95	-	Vdc
		10	9.95	-	9.95	10	-	9.95	-	Vdc
		15	14.95	-	14.95	15	-	14.95	-	Vdc
Input Voltage (Note 4) $(V_O = 4.5$ or $0.5V_{dc})$ $(V_O = 9.0$ or $1.0V_{dc})$ $(V_O = 13.5$ or $1.5V_{dc})$ $(V_O = 0.5$ or $4.5V_{dc})$ $(V_O = 1.0$ or $9.0V_{dc})$ $(V_O = 1.5$ or $13.5V_{dc})$	“0” Level V_{IL}	5.0	-	1.5	-	2.25	1.5	-	1.5	Vdc
		10	-	3.0	-	4.50	3.0	-	3.0	Vdc
		15	-	4.0	-	6.75	4.0	-	4.0	Vdc
	“1” Level V_{IH}	5.0	3.5	-	3.5	2.75	-	3.5	-	Vdc
		10	7.0	-	7.0	5.50	-	7.0	-	Vdc
		15	11.0	-	11.0	8.25	-	11.0	-	Vdc
Output Drive Current $(V_{OH} = 2.5V_{dc})$ $(V_{OH} = 4.6V_{dc})$ $(V_{OH} = 9.5V_{dc})$ $(V_{OH} = 13.5V_{dc})$ $(V_{OL} = 0.4V_{dc})$ $(V_{OL} = 0.5V_{dc})$ $(V_{OL} = 1.5V_{dc})$	Source I_{OH}	5.0	-1.2	-	-1.0	-1.7	-	-0.7	-	mAdc
		5.0	-0.25	-	-0.2	-0.36	-	-0.14	-	mAdc
		10	-0.62	-	-0.5	-0.9	-	-0.35	-	mAdc
		15	-1.8	-	-1.5	-3.5	-	-1.1	-	mAdc
	Sink I_{OL}	5.0	0.64	-	0.51	0.88	-	0.36	-	mAdc
		10	1.6	-	1.3	2.25	-	0.9	-	mAdc
		15	4.2	-	3.4	8.8	-	2.4	-	mAdc
		Input Current	I_{in}	15	-	± 0.1	-	± 0.00001	± 0.1	-
Input Capacitance ($V_{IN} = 0$)	C_{in}	-	-	-	-	5.0	7.5	-	-	pF
Quiescent Current (Per Package)	I_{DD}	5.0	-	5.0	-	0.005	5.0	-	150	Adc
		10	-	10	-	0.010	10	-	300	Adc
		15	-	20	-	0.015	20	-	600	Adc
Total Supply Current (Dynamic plus Quiescent, Per Package, $C_L = 50pF$ on all outputs, all buffers switching, Note 3, Note 5)	I_T	5.0	$I_T = (0.8 \text{ A/kHz}) f + I_{DD}$							Adc
		10	$I_T = (1.6 \text{ A/kHz}) f + I_{DD}$							Adc
		15	$I_T = (2.4 \text{ A/kHz}) f + I_{DD}$							Adc
Three State Leakage Current	I_{TL}	15	-	± 0.1	-	± 0.00001	± 0.1	-	± 3.0	Adc

Note 2. Data labeled “Typ” is not to be used for design purposes but is intended as an indication of the device’s potential performance.

Note 3. The formulas given are for the typical characteristics only at +25°C.

Note 4. Noise immunity specified for worst-case input combination.

Noise margin for both “1” and “0” = 1.0Vdc min @ $V_{DD} = 5V_{dc}$
 2.0Vdc min @ $V_{DD} = 10V_{dc}$
 2.5Vdc min @ $V_{DD} = 15V_{dc}$

Note 5. To calculate total supply current at loads other than 50pF:

$$I_T(C_L) = I_T(50pF) + 1 \times 10^{-3} (C_L - 50) V_{DD}f$$

where: I_T is in A (per package), C_L in pF, V_{DD} in Vdc, f in kHz is input frequency.

Switching Characteristics: ($C_L = 50\text{pF}$, $T_A = +25^\circ\text{C}$, Note 2)

Parameter	Symbol	V _{DD} Vdc	Min	Typ	Max	Unit
Output Rise Time $t_{TLH} = (3.0\text{ns/pF}) C_L + 25\text{ns}$ $t_{TLH} = (1.5\text{ns/pF}) C_L + 12\text{ns}$ $t_{TLH} = (1.1\text{ns/pF}) C_L + 8\text{ns}$	t_{TLH}	5.0	–	225	360	ns
		10	–	110	180	ns
		15	–	80	130	ns
Output Fall Time $t_{THL} = (1.5\text{ns/pF}) C_L + 47\text{ns}$ $t_{THL} = (0.75\text{ns/pF}) C_L + 24\text{ns}$ $t_{THL} = (0.55\text{ns/pF}) C_L + 17\text{ns}$	t_{THL}	5.0	–	130	200	ns
		10	–	65	100	ns
		15	–	50	80	ns
Turn-Off Delay Time $t_{PLH} = (0.9\text{ns/pF}) C_L + 211\text{ns}$ $t_{PLH} = (0.3\text{ns/pF}) C_L + 70\text{ns}$ $t_{PLH} = (0.23\text{ns/pF}) C_L + 54\text{ns}$	t_{PLH}	5.0	–	330	650	ns
		10	–	125	250	ns
		15	–	85	170	ns
Turn-On Delay Time $t_{PHL} = (2.7\text{ns/pF}) C_L + 184\text{ns}$ $t_{PHL} = (0.9\text{ns/pF}) C_L + 61\text{ns}$ $t_{PHL} = (0.68\text{ns/pF}) C_L + 47\text{ns}$	t_{PHL}	5.0	–	330	650	ns
		10	–	125	250	ns
		15	–	85	170	ns
3-State Output Delay Time “1” or “0” to High Impedance, and High Impedance to “1” or “0”	t_{PHZ} , t_{PLZ} , t_{PZH} , t_{PZL}	5.0	–	60	150	ns
		10	–	35	100	ns
		15	–	30	75	ns

Note 2. Data labeled “Typ” is not to be used for design purposes but is intended as an indication of the device’s potential performance.

Note 3. The formulas given are for the typical characteristics only at +25°C.

Truth Table

C	B	A	Inhibit	Disable	Z
0	0	0	0	0	X0
0	0	1	0	0	X1
0	1	0	0	0	X2
0	1	1	0	0	X3
1	0	0	0	0	X4
1	0	1	0	0	X5
1	1	0	0	0	X6
1	1	1	0	0	X7
DC	DC	DC	1	0	0
DC	DC	DC	DC	1	High Impedance

DC = Don’t Care

Pin Connection Diagram

